Quantum noise in the electromechanical shuttle: Quantum master equation treatment

D. Wahyu Utami,^{1[,*](#page-19-0)} Hsi-Sheng Goan,^{2[,†](#page-19-1)} C. A. Holmes,³ and G. J. Milburn⁴

¹School of Physical Sciences, The University of Queensland, QLD 4072, Australia

²*Department of Physics and Center for Theoretical Sciences, National Taiwan University, Taipei 10617, Taiwan*

3 *Department of Mathematics, School of Physical Sciences, The University of Queensland, QLD 4072, Australia*

⁴*Center for Quantum Computer Technology and Department of Physics, School of Physical Sciences, The University of Queensland,*

QLD 4072, Australia

(Received 6 October 2005; revised manuscript received 11 June 2006; published 21 July 2006)

We consider a type of quantum electromechanical system, known as the shuttle system, first proposed by Gorelik et al. [Phys. Rev. Lett. 80, 4526 (1998)]. We use a quantum master equation treatment and compare the semiclassical solution to a full quantum simulation to reveal the dynamics, followed by a discussion of the current noise of the system. The transition between tunneling and shuttling regime can be measured directly in the spectrum of the noise.

DOI: [10.1103/PhysRevB.74.014303](http://dx.doi.org/10.1103/PhysRevB.74.014303)

: $72.70 + m$, $73.23 - b$, 73.63 .Kv, $62.25 + g$

I. INTRODUCTION

Nanofabrication techniques, combined with single electronics, have recently enabled position measurements on an electromechanical oscillator to approach the Heisenberg limit.^{1[–3](#page-19-3)} In this paper we present a master equation treatment of a version of a quantum electromechanical system (QEMS), the charge shuttle, first proposed by Gorelik.⁴ In the original proposal a metallic grain is surrounded by elastic soft organic molecules and placed between two electrodes. This forms a single electron transistor (SET) with a movable island. The coupling between the vibration of the island and the tunneling onto the SET island dramatically alters the transport properties of the SET. The tunneling amplitudes between the reservoirs and the island are an exponential function of the separation between island and the reservoirs. If the island is oscillating with a non negligible amplitude, this separation is a function of the displacement of the island from equilibrium and thus the tunneling current is modulated by the motion of the island. When there is a nonzero charge on the island the applied electric field accelerates the island. As the electron number on the island is a stochastic quantity, the resulting applied force is itself stochastic, but constant for a given electron occupancy of the island. Assuming the restoring force on the island can be approximated as harmonic, we have a picture of a system moving on multiple quadratic potential surfaces, with differing equilibrium displacements, connected by conditional Poisson processes corresponding to tunneling of electrons on and off the island. The shuttle thus provides a fascinating example of a quantum stochastic system in which electron transport and vibrational motion are strongly coupled.

In this paper we idealize the island to a single quantum dot with only one quasibound electronic state. This corresponds to an extreme Coulomb blockade regime in which the energy required for double occupancy is not bound. This minimal model captures the essential quantum stochastic dynamics of the shuttle system. The quantum dot jumps between two quadratic potential surfaces, displaced from each other, corresponding to no electron on the island and one electron on the island. As noted by previous authors, the system exhibits rich dynamics including a fixed point to limit cycle bifurcation in which the average electron occupation number on the island exhibits a periodic square wave dependence.

Various versions of a charge shuttle system have been experimentally investigated. A review of the theoretical and experimental achievements in shuttle transport can also be found in the work of Shekhter *et al.*[5](#page-19-5) When a voltage bias is applied between the electrodes, a current quantization resulting from electron interactions with the vibrational levels for different voltage bias was found. By using C_{60} embedded between two gold electrodes, Park *et al.*[6](#page-19-6) have demonstrated that indeed there is current quantization for various bias voltage which results in a stair-like feature within the currentvoltage curve. Although because of its high frequency (around TH) and low amplitude oscillation, the molecule hardly shuttles between the electrodes in this setup, this experiment has provided key evidence of the involvement of vibrational levels in changing the properties of the current. This quantized conductance also was observed in experiment by Zhitenev *et al.*[7](#page-19-7) They utilize a metal single electron transistor attached to the tip of quartz rods as a scanning probe. Another experiment by Erbe *et al.*^{[8](#page-19-8)} combines a nanomechanical resonator with an electron island to produce a QEMS system. The experimental setup used by Erbe is similar to the one proposed by Gorelik.⁴ Huang *et al.* also reported the operation of a GHz mechanical oscillator.⁹

Several attempts to explain the behavior of the system have been offered both from classical and quantum point of view. Following the original paper by Gorelik *et al.*, [4](#page-19-4) the same group offered the analytical study using classical and stochastic method within the weak electromechanical coupling[.10](#page-19-10) A dynamical instability was found to exist above a certain critical voltage in the current-voltage relation which separates the "stationary regime" and the "shuttle regime." The first regime is when the electron tunnels straight into the dot from the source and off to the drain, without much involvement of the island movement. This is also called the tunnel regime. The C_{60} system lies within this tunnel regime. The other regime is when the island oscillates to accommodate the current flow, which was called the shuttle regime. However, measurement of average current alone cannot provide enough information to distinguish whether the system is in the shuttle regime or tunnel regime. It was shown that a calculation of the noise is needed in addition. By looking at the low frequency noise of the shuttle, the transition between these two regimes was investigated by Isacsson and Nord $¹¹$ </sup> also using classical approach.

One of the early attempts to investigate the system within the quantum limit is given by Aji *et al.*[12](#page-19-12) where electronicvibrational coupling is investigated both in elastic and inelastic electron transport by looking at the current-voltage relationship and conductance. Other properties of the transport within the shuttle system such as negative differential conductance have also been found¹³ although the derivation only considers terms linear in the position of the island. Various conditions, such as when the electron tunneling length is much greater than the amplitude of the zero point oscillations of the central island, have been investigated by Fedorets.¹⁴

Using phase space methods in terms of the Wigner func-tion, Jauho's group^{15,[16](#page-19-16)} identify the crossover from tunneling to shuttling regime in the limit of infinitely wide bias. The crossover was investigated as a function of the external damping. The shot noise signature of this transition was first obtained by finding the Fano factor at zero frequency.¹⁷ The fano factor is shown to be low within the shuttling regime. In a later paper by Flindt *et al.*, [18](#page-19-18) the full current noise spectrum was obtained as a function of damping coefficient. Peaks at integer multiple of the mechanical frequency were found. Another regime called the coexistence regime was identified. Within this region, tunneling and shuttling both occur. The current noise spectrum was calculated using a method different from that used in this paper. We compare the two methods in Sec. VI.

Another interesting property of the system is the existence of a dynamical instability with limit-cycle behavior which was found in a similar setup using a single metallic grain placed on a cantilever between two electrodes.¹⁰ This forms a three-terminal contact shuttle system. Classical analysis of the system points to the fact that this instability in the system leads to deterministic chaos. The semiclassical dynamics of the simpler case of the isolated island, the subject of this paper, was thoroughly investigated by Donarini.¹⁹

Another variation of the shuttle is offered by Armour and MacKinnon.²⁰ In this model the steady state current across a chain of three quantum dots system (one dot connected to each leads and one dot as vibrating island) was analyzed by looking at the eigenspectrum. Numerical simulation here considers 25 phonon levels, within the large bias limit. The three dot shuttle system was also investigated in a recent thesis of Donarini¹⁹ using a generalized master equation approach and looking at the Wigner distribution functions. The theory for zero frequency current noise in this array setup is investigated by Flindt *et al.*[21](#page-19-21)

In this paper we give a quantum master equation treatment of this quantum stochastic dynamical system, with particular attention to the shuttling and the current noise spectrum. First we investigate the dynamics of the system in the case of zero temperature. We then slightly extend this calculation to the finite temperature regime. We use the Quantum Optics Toolbox 22 to compare and contrast the well known semiclassical predictions to the full quantum dynamics. In

FIG. 1. Schematic representation of shuttling between a source and a drain through a quantum dot.

particular, we compare the picture of ensemble averaged dynamics of various moments with a "quantum trajectory" $23-27$ simulation of moments which has not been done by previous authors. A quantum trajectory is a concept taken from quantum optics to describe the conditional dynamics of the system conditioned on a particular history of stochastic events. Such conditional dynamics provide insight into the effect of quantum noise on the semiclassical prediction of regular electron shuttling on the limit cycle.

We begin by describing the complete Hamiltonian of the system. From this Hamiltonian we can derive the Master equation using the Born and Markov approximations. We then continue to derive the moments. Both semiclassical dynamics and the quantum simulation were investigated in Sec. III and IV, respectively. Here we identify the three regimes of the shuttling: the oscillatory regime, strongly damped regime and the coexistence regime with respect to various variables, notably the tunnel rates and the electromechanical coupling. We investigate the trajectories and the noise spectrum of the shuttle system.

II. THE MODEL

The system consists of a quantum dot "island" moving between two electrodes, the source and the drain as illustrated in Fig. [1.](#page-1-0) This is analogous to a quantum dot SET in which the island of the SET is allowed to oscillate and thus modulate the tunnel conductance between itself and the reservoirs. However unlike a SET we do not include a separate charging gate for the island. When a voltage bias is applied between the two electrodes, the electron from the source can tunnel onto the island and as the island moves closer to the drain the electron can tunnel off, thus producing a current. Here we assume that only one electronic level is available within the island, a condition of strong Coulomb blockade.

The electronic single quasibound state on the dot is described by Fermi annihilation and creation operators c, c^{\dagger} , which satisfy the anticommutation relation $cc^{\dagger} + c^{\dagger}c = 1$. While the vibrational degree of freedom is described by a displacement operator *xˆ* which can be written in terms of annihilation and creation operators a and a^{\dagger} , with the commutation relation *aa*†−*a*† *a*=1

$$
\hat{x} = \sqrt{\frac{\hbar}{2m\nu}} (a + a^{\dagger}).
$$
\n(1)

The Hamiltonian of the system is given by

$$
H = \hbar \omega_l c^{\dagger} c + U_c \hat{n}^2 \tag{2}
$$

$$
+\hbar v a^{\dagger} a \tag{3}
$$

$$
+\hbar\omega_{sk}a_{k}^{\dagger}a_{k}+\hbar\omega_{dk}b_{k}^{\dagger}b_{k}\tag{4}
$$

$$
-eE\hat{x}c^{\dagger}c\tag{5}
$$

+
$$
\sum_{k} [T_{sk}E_{-}(\hat{x})a_{k}c^{\dagger} + \text{H.c.}]
$$

+ $\sum_{k} [T_{dk}E_{+}(\hat{x})b_{k}c^{\dagger} + \text{H.c.}]$ (6)

$$
+\sum_{p}g(a^{\dagger}d_{p}+ad_{p}^{\dagger})+\sum_{p}\hbar\omega_{p}d_{p}^{\dagger}d_{p},
$$
\n(7)

where *E* is the electric field seen by an electron on the dot.

The first term of the Hamiltonian describes the energy of a single-electron quasibound state of the island. For the purpose of our simulation, we will scale other energies in terms of this island energy and thus conveniently set $\hbar \omega_I = 1$. The Coulomb charge energy U_c is the energy that is required to add an electron when there is already one electron occupying the island $(\hat{n}=c^{\dagger}c)$. This energy is assumed to be large enough so that no more than one electron occupies the island at any time. This is the Coulomb blockade regime. In this regime it is better to regard the island as a single quantum dot rather than a metal island and we will refer to it as such in the remainder of this paper. The free Hamiltonian for the oscillator is described in term (3) (3) (3) , where ν is the frequency of the mechanical oscillation of the quantum dot. The electrostatic energy of electrons in the source (s) and drain (d) reservoirs is written as term ([4](#page-2-1)), with a_k , a_k^{\dagger} and b_k , b_k^{\dagger} the annihilation and creation operator for the electron in the source and drain, respectively. Term ([5](#page-2-2)) describes the electrostatic coupling between the oscillator and charge while term (6) (6) (6) represents the source-island tunnel coupling and the drain-island tunnel coupling. In the shuttle system, the island of the SET is designed to move between the source and the drain terminal with an amplitude or fluctuation comparable to the distance of the island to the lead. Thus we introduce the term

$$
E_{\pm}(\hat{x}) = e^{\pm \hat{x}/\lambda} \tag{8}
$$

$$
=e^{\pm\eta(a+a^{\dagger})},\tag{9}
$$

where λ is the tunneling length with

$$
\eta = \left(\frac{\hbar}{2mv}\right)^{1/2} \frac{1}{\lambda} \tag{10}
$$

to account for the change in the tunneling rate to the left and the right lead as the position of the shuttle varies.

The last term (7) (7) (7) describes the coupling between the oscillator and the thermomechanical bath responsible for damping and thermal noise in the mechanical system in the rotating wave approximation.²⁸ We include it in order to bound the motion under certain bias conditions.

We now obtain a closed evolution for the system of quantum dot plus oscillator by tracing out over the degrees of freedom in the leads. A Markov master equation for the island-oscillator system can then be derived in the Born and Markov approximation using standard techniques.²⁹ If we assume the vibrational frequency of the oscillator is slow compared to bath relaxation time scales, we arrive at

$$
\dot{\rho} = -i\nu[a^{\dagger}a,\rho] + i\chi[(a+a^{\dagger})c^{\dagger}c,\rho] + \gamma_L\{f(\hbar\omega_I - \mu_L)\mathcal{D}[c^{\dagger}E_{-}(\hat{x})]\rho + [1 - f(\hbar\omega_I - \mu_L)]\mathcal{D}[cE_{-}(\hat{x})]\rho\} + \gamma_R\{f(\hbar\omega_I - \mu_R)\mathcal{D}[c^{\dagger}E_{+}(\hat{x})]\rho + [1 - f(\hbar\omega_I - \mu_R)]\mathcal{D}[cE_{+}(\hat{x})]\rho\} + \kappa(\bar{n}_p + 1)\mathcal{D}[a]\rho + \kappa\bar{n}_p\mathcal{D}[a^{\dagger}]\rho,
$$
\n(11)

with $\chi = eE \eta \lambda$ and \bar{n}_p is the mean phonon number for the vibrational damping reservoir. We also have defined

$$
\mathcal{D}[A]\rho = A\rho A^{\dagger} - \frac{1}{2}(A^{\dagger}A\rho + \rho A^{\dagger}A),\tag{12}
$$

where *f* is the Fermi function $f(\epsilon) = 1/(e^{\epsilon/T_{\text{el}}}+1)$. This Fermi function has an implicit dependence on the temperature T_{el} of the electronic system and the bias conditions between the source and the drain. The terms γ_L , γ_R describe the rates of electron tunneling from the source to the dot and dot to drain, respectively, as a function of island energy and the left or right bias as derived and defined in Ref. [29.](#page-19-26) We have implicitly ignored cotunneling and higher order scattering events, so this equation applies under weak bias and weak tunneling conditions. The final two terms proportional to κ describe the damping of the oscillator, where \bar{n}_p $=1/(e^{\hbar v/k_B T-1})$ and *T* are, respectively, the mean excitation and the effective temperature of a thermal bath responsible for this damping process. Thermal mechanical fluctuations in the metal contacts of the source and drain cause fluctuations in position of the center of the trapping potential confining the island, that is to say small, fluctuating linear forces act on the island. For a harmonic trap, this appears to the oscillator as a thermal bath. However such a mechanism is expected to be very weak. This fact, together with the very large frequency of the oscillator, justifies our use of the quantum optical master equation (as opposed to the Brownian motion master equation) to describe this source of dissipation.²⁸

In order to discuss the phenomenology of this system we first consider a special case. Under appropriate bias conditions and very low temperature, the quasi bound state on the island is well below the Fermi level in the source and well above the Fermi level in the drain. The master equation then takes the "zero temperature" form

$$
\dot{\rho} = -i\nu[a^{\dagger}a,\rho] + i\chi[(a+a^{\dagger})c^{\dagger}c,\rho] + \gamma_L \mathcal{D}[c^{\dagger}E_{-}(\hat{x})]\rho + \gamma_R \mathcal{D}[cE_{+}(\hat{x})]\rho + \kappa(\bar{n}_p + 1)\mathcal{D}[a]\rho + \kappa \bar{n}_p \mathcal{D}[a^{\dagger}]\rho.
$$
\n(13)

Here we take the assumption of weak tunneling such that the energy of the occupied dot lies between the two Fermi energies of the leads. The terms proportional to γ_L and γ_R describe two conditional Poisson processes $dN_L(t)$, $dN_R(t)$ in

which an electron tunnels onto or off the island. The average rate of these processes is given by $30-33$

$$
\begin{array}{l} \mathcal{E}\big[dN_L(t)\big]=\gamma_L {\rm Tr}\big[E_-(\hat{x})c^\dagger\rho cE_-(\hat{x})\big]dt,\\ \\ \mathcal{E}\big[dN_R(t)\big]=\gamma_R {\rm Tr}\big[E_+(\hat{x})c\rho c^\dagger E_+(\hat{x})\big]dt, \end{array}
$$

where $\mathcal E$ refers to a classical stochastic average. Using the cyclic property of trace and the definition in Eq. (9) (9) (9) we see that

$$
\mathcal{E}[dN_L(t)] = \gamma_L \langle e^{-2\hat{x}/\lambda} c c^{\dagger} \rangle dt, \qquad (14)
$$

$$
\mathcal{E}[dN_R(t)] = \gamma_R \langle e^{2\hat{x}/\lambda} c^{\dagger} c \rangle dt. \tag{15}
$$

It is now possible to see that the current through the dot will depend on the position of the oscillator. Under appropriate operating conditions (discussed below) we can use this dependence to configure the device as a position sensor or weak force detector. For a symmetric case where the tunneljunction capacitances are almost the same $C_L \approx C_R$ (neglecting the position dependence of the capacitances), the Ramo-Shockley theorem indicates that the average current in the circuit can be given by

$$
I(t) = \mathcal{E}[i(t)] = \frac{e}{2} \left[\mathcal{E} \left(\frac{dN_L(t)}{dt} \right) + \mathcal{E} \left(\frac{dN_R(t)}{dt} \right) \right].
$$
 (16)

If $\eta \ll 1$ and $\gamma_L = \gamma_R = \gamma$ we may write this as

$$
I(t) \approx e \gamma/2 + \frac{e\gamma}{\lambda} \langle \hat{x}(c^{\dagger}c - cc^{\dagger}) \rangle + \frac{e\gamma}{\lambda^2} \langle \hat{x}^2 \rangle \tag{17}
$$

$$
=e\,\gamma/2+\frac{e\,\gamma}{\lambda}(\langle\hat{x}\rangle_1-\langle\hat{x}\rangle_0)+\frac{e\,\gamma}{\lambda^2}\langle\hat{x}^2\rangle,\qquad\qquad(18)
$$

where

$$
\langle \hat{x} \rangle_k = \text{Tr}_{\text{osc}}[\hat{x} \langle k | \rho | k \rangle] \tag{19}
$$

with $k=0,1$ the occupation number states for the dot and where "osc" indicates a trace with respect to the oscillator Hilbert space alone. It is apparent that $\langle \hat{x} \rangle_k$ refers to the average position of the oscillator conditioned on a particular occupation of the dot. Clearly the average current through the system depends on the position of the oscillating dot. However the dependence on the first moment of position may be very weak. If the tunnel rates through the dot are much larger than all other time scales we expect that the occupation of the dot will reach an equilibrium value of $\frac{1}{2}$ quickly. In this case the term linear in position will be very small, leaving only a quadratic dependence. However if it can be arranged that $\gamma_L \neq \gamma_R$, there will be a direct dependence of the current on the oscillator position. To clarify this situation we first look at a semiclassical description of the dynamics.

III. SEMICLASSICAL DYNAMICS

The master equation Eq. (11) (11) (11) enables us to calculate the coupled dynamics of the vibrational and electronic degrees of freedom. The equations of motion for the occupation number on the dot and the average phonon number are

$$
\frac{d\langle c^{\dagger}c\rangle}{dt} = \gamma_L[f_L\langle cc^{\dagger}e^{-2\hat{x}/\lambda}\rangle - (1 - f_L)\langle c^{\dagger}ce^{-2\hat{x}/\lambda}\rangle] \n+ \gamma_R[f_R(\langle cc^{\dagger}e^{2\hat{x}/\lambda}\rangle - (1 - f_R)\langle c^{\dagger}ce^{2\hat{x}/\lambda}\rangle], \quad (20) \n\frac{d\langle a^{\dagger}a\rangle}{dt} = \gamma_L\eta^2[f_L\langle cc^{\dagger}e^{-2\hat{x}/\lambda}\rangle + (1 - f_L)\langle c^{\dagger}ce^{-2\hat{x}/\lambda}\rangle] \n+ \gamma_R\eta^2[f_R\langle cc^{\dagger}e^{2\hat{x}/\lambda}\rangle + (1 - f_R)\langle c^{\dagger}ce^{-2\hat{x}/\lambda}\rangle]
$$

$$
-i\chi\langle (a-a^{\dagger})c^{\dagger}c\rangle + \kappa\overline{n} - \kappa\langle a^{\dagger}a\rangle, \tag{21}
$$

where the Fermi factors are defined by $f_{\alpha} = f(\omega_I - \mu_{\alpha})$ with $\alpha = L$,*R* and μ_{α} is the chemical potential in the source (α $=L$) and drain $(\alpha = R)$ and $\hbar \omega_I$ is the energy of the quasi bound state on the dot. The equation of motion for the average amplitude is relatively simple:

$$
\frac{d\langle a \rangle}{dt} = -i\nu\langle a \rangle - \frac{1}{2}\kappa\langle a \rangle + i\chi\langle c^{\dagger}c \rangle \tag{22}
$$

which is the equation of motion for a damped oscillator with time dependent driving. Unfortunately these first order number moments are coupled into higher order moments generating a hierarchy of coupled equations. A semiclassical approximation to the dynamics may be defined by factorizing moments for electronic and vibrational degrees of freedom. This discards quantum correlations and thus is certainly not the appropriate way to describe a quantum limited measurement. However, it does enable us to see the essential features of the dynamical character of this problem. We will return to the full quantum problem in the next section.

We begin the semiclassical approach by factoring moments of oscillator and electronic coordinates, for example, of $\langle cc^{\dagger}E_{-}^{2} \rangle$ into $\langle cc^{\dagger} \rangle \langle E_{-}^{2} \rangle$, to obtain

$$
\frac{d\langle c^{\dagger}c\rangle}{dt} = \gamma_L(\langle E_{-}^2\rangle f_L - \langle c^{\dagger}c\rangle \langle E_{-}^2\rangle) + \gamma_R(\langle E_{+}^2\rangle f_R - \langle c^{\dagger}c\rangle \langle E_{+}^2\rangle). \tag{23}
$$

Using the definitions

$$
\hat{x} = \eta \lambda (a + a^{\dagger}), \quad \hat{p} = -i \frac{\hbar}{2 \eta \lambda} (a - a^{\dagger})
$$

we can write the semiclassical equations in terms of position $x = \langle \hat{x} \rangle$, momentum $p = \langle \hat{p} \rangle$ and electron number $n = \langle c^{\dagger} c \rangle$,

$$
\frac{dn}{dt} = \gamma_L (e^{-2x/\lambda} f_L - n e^{-2x/\lambda}) + \gamma_R (e^{2x/\lambda} f_R - n e^{2x/\lambda}), \quad (24)
$$

$$
\frac{dx}{dt} = \frac{p}{m} - \frac{\kappa}{2}x,\tag{25}
$$

$$
\frac{dp}{dt} = -mv^2x - \frac{\kappa}{2}p + \chi\sqrt{2m\nu\hbar n},\qquad(26)
$$

where we have made the further factorization $\langle E_{\pm}^2(\hat{x})\rangle$ $=e^{\pm 2x/\lambda}$. These results agree with the previous classical equations obtained by Isacsson, 10 in the case of zero gate voltage on the island. We will carefully consider the regime of validity of these semiclassical equations in Sec. V. For now we note that factorizing vibrational and electronic degrees of freedom ignores any entanglement between these systems, while factorizing the exponential assumes the oscillator is very well localized in position.

In the zero temperature limit and appropriate bias we have that $f_L = 1$, $f_R = 0$. The semiclassical equations of motion then take the form

$$
\frac{dn}{dt} = \gamma_L (1 - n)e^{-4\eta X} - \gamma_R n e^{4\eta X},\qquad(27)
$$

$$
\frac{d\alpha}{dt} = -i\nu\alpha - \frac{\kappa}{2}\alpha + i\chi n\tag{28}
$$

with

$$
\alpha = \langle a \rangle = \langle \hat{x} \rangle / (2\lambda \eta) + i \langle \hat{p} \rangle \lambda \eta / \hbar \equiv X + iY.
$$

The system of equations (27) (27) (27) and (28) (28) (28) has a fixed point, which undergoes a Hopf bifurcation.

To see this we begin by scaling the parameters by ν and η , $\frac{\gamma}{\nu} \to \gamma$, $\frac{\kappa}{\nu} \to \kappa$, $\frac{\gamma \chi}{\nu} \to \chi$, and $\nu \to 1$ by scaling time $\tau = \nu t$; and redefining *X* and *Y* by letting $\alpha = \eta(X + iY)$. Then

$$
\frac{dn}{d\tau} = \gamma_L (1 - n)e^{-4X} - \gamma_R n e^{4X},
$$
 (29)

$$
\frac{d\alpha}{d\tau} = -i\alpha - \frac{\kappa}{2}\alpha + i\chi n. \tag{30}
$$

The fixed point is given implicitly by

$$
n_{*} = \frac{\gamma_{L}e^{-4X_{*}}}{\gamma_{L}e^{-4X_{*}} + \gamma_{R}e^{4X_{*}}} = \frac{1}{1 + \frac{\gamma_{R}}{\gamma_{L}}} ,
$$
 (31)

$$
X_* = \frac{\chi}{1 + \left(\frac{\kappa}{2}\right)^2} n_*,\tag{32}
$$

$$
Y_* = \frac{\chi_2^{\kappa}}{1 + \left(\frac{\kappa}{2}\right)^2} n_* \tag{33}
$$

from which we can see that it must satisfy

$$
\chi = X_* \left[1 + \left(\frac{\kappa}{2}\right)^2 \right] \left(1 + \frac{\gamma_R}{\gamma_L} e^{8X_*} \right). \tag{34}
$$

At the Hopf bifurcation the fixed point loses stability and a limit cycle is created. To see this, first obtain the linearized matrix about the stationary point

FIG. 2. Illustration of two possible type of Hopf bifurcation in the shuttle system with varying coupling χ , (a) supercritical and (b) subcritical and saddle node bifurcation of the limit cycles.

$$
DF = \begin{pmatrix} -A_{*} & -\frac{8\gamma_{L}\gamma_{R}}{A_{*}} & 0 \\ 0 & -\frac{\kappa}{2} & 1 \\ \chi & -1 & -\frac{\kappa}{2} \end{pmatrix},
$$

where

$$
A_{*} = \gamma_{L} e^{-4X_{*}} + \gamma_{R} e^{4X_{*}}.
$$

The stability of the fixed point is determined by the eigenvalues of this matrix. If one or more of the eigenvalues have positive real part the fixed point is unstable. For complex eigenvalues the transition between stable and unstable occurs when the eigenvalues are pure imaginary. Here this is when

$$
\chi = \chi_h = \frac{A \ast \kappa \left[A \ast (A \ast + \kappa) + 1 + \left(\frac{\kappa}{2} \right)^2 \right]}{8 \gamma_L \gamma_R}.
$$
 (35)

At $\chi = \chi_h$ the eigenvalues are $-(A_* + \kappa), \pm i\mu$, where μ $=\sqrt{A_{*}\kappa+1+({\kappa\over2})^2}$ and the fixed point has a one-dimensional stable manifold and a two-dimensional center manifold. For $\chi < \chi_h$ the fixed point is stable and for $\chi > \chi_h$ it is unstable. This suggests a Hopf bifurcation which can either be a subcritical or supercritical bifurcation. A schematic diagram of the two bifurcations are shown in Fig. [2.](#page-4-2) It is necessary to work out the stability coefficient to determine if it is subcritical, creating an unstable limit cycle or supercritical, creating a stable limit cycle. This involves some algebra. First transform the system in the vicinity of the fixed point to normal form via the matrix of eigenvectors *P*

Then in normal form coordinates $\mathbf{u} = P^{-1}(n - n^*, X - X^*)$ $(Y - Y_*)^T$ the system becomes

$$
\frac{d\mathbf{u}}{d\tau} = \begin{pmatrix} -(A_* + \kappa) & 0 & 0 \\ 0 & 0 & -i\mu \\ 0 & i\mu & 0 \end{pmatrix} \mathbf{u} + \mathbf{g}Nl(\mathbf{u}) + 8\gamma_L\gamma_R\mathbf{f}(\chi - \chi_h)
$$

×(u₁ + u₃), (36)

where **g** and **f** are column vectors, whose entries are *gi* $= P_{i1}^{-1}$, $f_i = P_{i3}^{-1}$. *Nl*(**u**) is a scalar nonlinear function of *u_i* obtained by perturbation. To cubic order in *ui*

$$
NI(\mathbf{u}) = -4n'X'\sqrt{A_*^2 - 4\gamma_L\gamma_R} - 8n'X'^2A_* - \frac{64\gamma_L\gamma_RX'^3}{3A_*},
$$

where

$$
(n', X', Y')^T = P\mathbf{u}^T.
$$

Now the limit cycle bifurcates into the center manifold which is tangent to the $u_1=0$ plane. So if $u_1=h(u_2, u_3)$ is the equation of the center manifold through $(0,0,0)$ at $\chi = \chi_h$, then $h(0,0)=0$ and $(\partial h/\partial u_i)(0,0)=0$. This means that a Taylor series approximation to the center manifold will have no constant or linear term and so the first nonzero terms are of quadratic order in *ui* and

$$
h(u_2, u_3) = a_{20}u_2^2 + a_{11}u_2u_3 + a_{02}u_3^2 + \text{higher order terms},
$$

for some a_{20} , a_{11} , and a_{02} . Now differentiating $u_1 = h(u_2, u_3)$ gives

$$
\frac{du_1}{d\tau} = \frac{\partial h}{\partial u_2}\frac{du_2}{d\tau} + \frac{\partial h}{\partial u_3}\frac{du_3}{d\tau}.
$$

On the center manifold $\frac{du_i}{d\tau}$ ($h(u_2, u_3)$, u_2, u_3) are functions of u_2 and u_3 only, so this equation can be used to calculate the coefficients $a_{i,j}$ in the Taylor series approximation to $h(u_2, u_3)$ recursively, by equating coefficients of like powers of u_2 and u_3 . Once $h(u_2, u_3)$ is found this can be fed back into the equations of motion for u_2 and u_3 to obtain the approximate equations of motion on the center manifold. Finally the stability coefficient for a two dimensional system in normal form³⁴ is $a = \frac{1}{16}(f_{xxx} + g_{xy} + f_{xyy} + g_{yyy}) + \frac{1}{16\omega}[f_{xy}(f_{xx} + f_{yy}) - g_{xy}(g_{xx} + g_{yy}) - f_{xx}g_{xx} + f_{yy}g_{yy}]$ evaluated at (0,0), where here $\omega = \mu = \sqrt{A_{*}\kappa + 1 + (\frac{\kappa}{2})^{2}}$. The subscripts indicate partial derivatives of function *f* or *g* with respect to the variables *x* and *y*. For instance f_{xx} , f_{xxx} is a shorthand for second and third derivative of function *f* with respect to *x*. Here the stability coefficient must be calculated numerically because the posi-tion of fixed point is only known implicitly via Eq. ([34](#page-4-3)).

Figure [3](#page-5-0) plots χ_h for various fixed values of γ_R as a func-

tion of γ_L . The line is solid where the stability coefficient is negative, implying a supercritical Hopf bifurcation and dashed where it is positive, implying a subcritical Hopf bifurcation.

At a supercritical bifurcation a stable limit cycle bifurcates from the fixed point, existing for $\chi > \chi_h$. At a subcritical an unstable limit cycle bifurcates from the fixed point, existing for $\chi < \chi_h$. Continuity of solutions as the parameter γ_L is changed suggests that the stable limit cycle existing for $\chi > \chi_h$ above the solid critical line also exists above the dashed line. Numerical evidence shows this to be the case and that it continues to exist well below the dashed line, eventually being annihilated in a saddle-node bifurcation with the unstable limit cycle created in the subcritical Hopf bifurcation at the dashed line. For $\gamma_R = 5$ and $\gamma_L = 1.01$ the Hopf bifurcation occurs at χ_h =0.42650636 and the saddle node bifurcation at χ_{SN} =0.315. A glance at Fig. [3,](#page-5-0) where a vertical gray line indicates the range of χ for $\gamma_R = 5$ and γ_L =1.01 for which there are two limit cycles shows that there is a significant parameter region, where two limit cycles coexist.

In general for fixed γ_R the stability coefficient is positive for small and very large γ_L and negative in between. This means that if γ_L and γ_R are about 1, say, a stable limit cycle bifurcates and is present for $\chi > \chi_h$. But if (γ_L / γ_R) is much less than 1, a more complicated situation may arise for χ $\langle \chi_h \rangle$, where an unstable limit cycle exists close to the critical point surrounded by a stable limit cycle.

FIG. 3. Plot of χ_h for various fixed values of γ_R as a function of γ_L . The line is solid where the Hopf bifurcation is supercritical and dashed where it is a subcritical Hopf bifurcation.

We then solved numerically the full system of equations, Eqs. (27) (27) (27) and (28) (28) (28) , for various values of the parameters. In the shuttling regime the electron number on the dot $n(t)$ exhibits a square wave dependence as a single electron is carried from source to drain, where it tunnels onto the drain and the dot returns empty to the source to repeat the cycle. This is shown as the thin line in Fig. $7(a)$ $7(a)$. The effect of shuttling generally occurs when the maximum displacement of the island is quite large, and where the strength of the tunneling depends strongly on the position of the island $(\lambda \text{ small})$. In the shuttling regime at the time after the electron jumps in until it leaves the shuttle to the drain, the electron number on the dot is constant. This gives, from Eq. (27) (27) (27) , an implicit relation between the shuttle position and the dot occupation

$$
n(X) = \frac{\gamma_L e^{-4\eta X}}{\gamma_L e^{-4\eta X} + \gamma_R e^{4\eta X}}.\tag{37}
$$

Near the equilibrium point $X=0$, this implies that for γ_L $=\gamma_R$, *n*=0.5. Away from the equilibrium point we have that

$$
n(X) = \begin{cases} 0 & X > 0, \\ 1 & X < 0. \end{cases}
$$
 (38)

This behavior is evident in the semiclassical dependence of $n(t)$ which we will compare with the numerical result in the next section.

A condition for shuttling is given also by Gorelik⁴ by specifying the requirement for the amplitude of the shuttle oscillation to be much bigger than the tunneling length λ . Donarini¹⁹ set the shuttling condition as to when the mechanical relaxation rate is much smaller than the mechanical frequency and also that the average injection and ejection rate is approximately equal to the mechanical frequency of the oscillator. The quantum dynamics may be determined by solving the master equation in the phonon number basis of the oscillator and the charge basis for the dot. It is necessary to truncate the phonon number basis high enough to include the amplitude of the limit cycle.

We use this semiclassical analysis to guide us through in selecting an appropriate set of values for our numerical quantum simulation. The problem in identifying the shuttling regime itself will be addressed in Sec. V.

To overcome the numerical difficulties with simulating large number of phonon levels for the quantum case described in Sec. V later, we choose a set of values of χ and η which will give a rather small limit cycle in the semiclassical approximation in Fig. [7.](#page-9-0) The accuracy of the semiclassical simulation is dependent on λ as can be seen in Sec. V by comparing the factorized and unfactorized result from the numerical method.

We now return to consider the dependence of the total current on the oscillator position. The total current through the device is given by Eq. (16) (16) (16) . In the semiclassical approximation this is given by

$$
I_T(t) = \frac{\gamma_L}{2} (1 - n) e^{-4\eta X} + \frac{\gamma_R}{2} e^{4\eta X} n.
$$
 (39)

At the fixed point region, this *n* can be substituted by *n** given in Eq. (31) (31) (31) to give

FIG. 4. (Color online) Current versus steady state position of the oscillator for various combination of η and χ with varying ratio of γ_L and γ_R along each curve. Here we have chosen κ =0.2 (a) η $= 0.3, \chi = 0.3$, (b) $\eta = 0.03, \chi = 0.3$, (c) $\eta = 0.03, \chi = 0.5$. Bold lines are results from the full quantum simulation and thin lines for the semiclassical approximations.

$$
I_T = \frac{\gamma_L \gamma_R}{\gamma_L e^{-4\eta X_*} + \gamma_R e^{4\eta X_*}}.\tag{40}
$$

When η is small, we can simplify the current further to

$$
I_T = \frac{\gamma_L \gamma_R}{\gamma_L + \gamma_R - 4\eta X_*(\gamma_L - \gamma_R)}.\tag{41}
$$

Here we need to remember that the tuneling rates γ_L and γ_R determine the steady state position of *X**. We can express, from Eqs. ([31](#page-4-4)) and ([32](#page-4-5)) the tunneling rates γ_R as

$$
\gamma_R = \frac{\gamma_L (B - X_*)(1 - 4\,\eta X_*)}{X_*(1 + 4\,\eta X_*)},\tag{42}
$$

where for simplicity we have set

$$
B = \frac{\chi \nu}{\nu^2 + (\kappa/2)}.\tag{43}
$$

We can thus rewrite the current

$$
I_T = \frac{\gamma_L (B - X_*)}{B + 4 \eta X_*}.
$$
 (44)

We can see that when η is small the current I_T is linearly dependent on the fixed point position X^* , with a slope of $\frac{-\gamma_L}{B}$.

We check this result using the full quantum simulation [Eqs. (20) (20) (20) and (21) (21) (21)] and compare it with the result of the semiclassical current (40) (40) (40) . We plot the result for various combination of η and χ in Fig. [4.](#page-6-1) For each condition, we vary the ratio of γ_R to γ_L to give the plotted curve. As we can see from Figs. $4(b)$ $4(b)$ and $4(c)$, the current is indeed linearly proportional to the steady state position of the oscillator when η small. In this case, the semiclassical expression of the current given above in Eq. (44) (44) (44) is a very good approximation of the actual current.

FIG. 5. (Color online) Plot of the electron occupation number in the island for various tunneling rate γ_L in a logarithmic scale when $\eta=0.3$, $\chi=0.5$, $\nu=1$, κ $=0.05$.

IV. SOLVING MASTER EQUATION NUMERICALLY

With the help of the Quantum Optics Toolbox, 22 we can solve the master equation directly by finding the time evolution of the density matrix. This was done by preparing the Liouvillian matrix in Matlab and solving the differential equation given the initial conditions.

The expectation values for any desired quantities such as the electron number $\langle c^{\dagger}c \rangle$, the phonon number $\langle a^{\dagger}a \rangle$, position $\langle x \rangle$, and the momentum $\langle p \rangle$ of the oscillator can be calculated by tracing the product of these quantities with density matrix ρ . The result can then be plotted against time. The same method can be applied to calculate the steady state solution of the expectation values using ρ_{ss} .

The initial state of the system has been set up to incorporate the two electron levels, namely the occupied and empty state, combined with *N* levels of phonon. The number of phonon levels included determines the accuracy of the calculation. Of course, the more phonon levels included the more accurate the simulation will be. However, only a limited number of phonon levels can be considered. This is due to the limited computer memory that is available and also considering the calculation time which will be significantly higher for larger *N*. Thus we try to find the minimum number of phonon levels which gives convergent results. This will ensure that the simulation still has a reasonably accurate solution. Donarini¹⁹ used the Arnoldi iteration³⁵ to find the stationary solution of the matrix to overcome this memory problem. However here we have proceeded without, in the hope of looking at not only the stationary solution but also the dynamical evolution of the shuttle.

The behavior of the shuttle depends strongly on the rate of electron jump between the island and the leads. We investigate this by looking at the variation in the electron number expectation $\langle c^{\dagger} c \rangle$ at various rates γ_L , γ_R . This is shown in

Fig. [5](#page-7-0) in which we have set γ_L to be equal to γ_R . When γ_L , γ_R are small, the electron number slowly increases until it reaches the steady state condition. In the region where the values of γ_L , γ_R are close to the frequency of the island, oscillation starts to occur, and depending on the damping that was set, the electron number can reach a steady oscillation putting the system well in the oscillatory regime. When γ_L , γ_R are very large compared to other frequency scales in the system, we will arrive at the strongly damped regime of the shuttle (see Sec. V B), where the jump rate of the electron is fast enough to damp the oscillations in the electron occupation number of the island. Since we set γ_L to be equal to γ_R the steady state happens at $\langle c^{\dagger} c \rangle = 0.5$.

Similarly the behavior of the shuttle also changes according to η , as described in Fig. [6.](#page-8-0) At $\eta=0$ the electron occupation number grows to a steady state. As we increased η further, the oscillations start to occur with increasing amplitude. Here we use 100 phonon levels for the numerical calculation.

A. Oscillatory regime

The oscillatory regime will occur when the oscillation caused by the electron jump rate introduces continued kicks on the island. This happens when the jump rate is close to the oscillation frequency of the island $(\gamma_L \approx \nu)$. By setting an appropriate damping to this oscillation (κ) , there exists a condition where the island will keep oscillating between the leads. With this setup, the system will be in the shuttle regime.

We then choose a set of parameters where the system shows the behavior of a shuttle, that is a continued oscillation of the electron number along with the oscillation of the island position. To ensure the convergence of the numerical solution, we use a smaller value of η that will still give a

FIG. 6. (Color online) Plot of the electron occupation number in the island for various values of η when $\gamma_L = \gamma_R = 1$, $\chi = 0.5$, $\nu = 1$, κ =0.05.

shuttling behavior. We choose a combination of η and χ that will give the smallest limit cycle to minimize the truncation error.

Within the region where the limit cycle exists, we can plot the electron expectation number against the average position and momentum and observe the shape of the limit cycle. We explored both the full density matrix simulation and the semiclassical solution to be compared. From the result (Fig. [7](#page-9-0)), the quantum simulation appears to be more damped than its semiclassical counterpart. This is due to the effect of the noise. This slight difference can also be caused by the dependence of the electron number on its correlation with the position that was ignored in the semiclassical case.

To check this we have plotted the difference between the factorized and unfactorized moment at this particular variable combination (Fig. 8). The time range in which the difference in the factorized and unfactorized occurs agrees well with the time range when the semiclassical and the quantum simulation disagree in Fig. [7.](#page-9-0) This disagreement happens at the time when the shuttle is in transition between the zero and one electron occupation number.

Of course the truncation will pose some inaccuracy in the quantum simulation at a longer time. However we have checked that this is not the case at least for a short period of time by comparing it with a simulation that includes a larger phonon number.

To investigate the effect of η on the correlation between the factorized and unfactorized moments, we can plot $\langle cc^{\dagger}(a+a^{\dagger}) \rangle$ and $\langle cc^{\dagger} \rangle \langle a+a^{\dagger} \rangle$. We can see from Fig. [9,](#page-10-1) that the semiclassical approximation agrees with the quantum simulation under the condition that η is small enough. As η increases, the evidence of this difference becomes noticeable. This difference oscillates with peaks located at times when electron jumps happen, that is when the oscillator is near the equilibrium position.

As opposed to what the name "electron shuttle" suggests, the dynamics in the shuttle regime, for the parameters specified in Fig. [7,](#page-9-0) is not similar to a conventional shuttle which picks up an electron when it is closest to the source and drops the electron when it is closest to the drain, as also suggested by Nord *et al.*[36](#page-19-31) Looking at the rate of the average electron number and the average current in the source Fig. $7(a)$ $7(a)$, this is certainly not the case. The shuttle picks up an electron near an average displacement of zero, slightly towards the source, and continues to travel closer to the source electrodes. It then oscillates back and drops the electron at a slightly displaced average position from equilibrium towards the drain electrode. The shuttle then continues to get closer to the drain before oscillating back to repeat the cycle.

An important distinction must be made between the dynamics of the averages derived from solving the master equation and a dynamics conditioned on a particular history of tunneling events. This distinction is already suggested by inspecting the average electron number as a function of time. In any actual realization of the stochastic process, the number of electrons on the dot is either zero or one, yet the ensemble average occupation number varies smoothly between zero and one. The reason for this is that the actual times at which transitions between the two states take place fluctuates.

We can more easily appreciate this distinction using an alternative approach to understanding the dynamics based on "quantum trajectories." The quantum trajectory method (sometimes called the Monte Carlo method) first introduced in quantum optics is a method of looking at the evolution of a system conditioned on the results of measurements made on that system[.24](#page-19-32)[,25,](#page-19-33)[30–](#page-19-27)[33](#page-19-28)[,37,](#page-19-34)[38](#page-19-35) This method will allow one to monitor "events" such as the jump of an electron to the island which causes the displacement kick on an oscillator.

To explain the concept of conditional dynamics assume for simplicity that the zero temperature limit applies, so that the bound state of the dot is well below the Fermi level in the source and well above the Fermi level in the drain. The irreversible dynamics are then conveniently described in terms of two conditional Poisson jump processes with rates defined in Eqs. (14) (14) (14) and (15) (15) (15) . The jump process (14) can only occur if there are no electrons on the dot, and the jump process (15) (15) (15) can only occur if there is an electron on the dot. In the case that there is no electron on the dot, the quantum dot moves in a quadratic potential centered on the origin. In the case that there is an electron on the dot, the non-zero electrostatic force means the quantum dot oscillates in a quadratic potential displaced from the origin by $X_0 = \chi / \nu$. We thus have a picture of a system moving on one or the other potential surfaces interrupted by jumps between them. This is schematically illustrated in Fig. [10.](#page-10-2) Due to the exponential dependence of the jump rates on position [see Eqs. (14) (14) (14) and (15) (15) (15)], the process $dN_L(t)$ is vastly more likely to occur when $X \leq 0$ and conversely, the jump process $dN_R(t)$ is much more likely to occur when $X > 0$. This means that the jump processes are an indication of which side of *X*=0 the dot is located.

With this interpretation we can easily describe the conditional dynamics of the shuttle conditioned on a history of jump processes. In quantum optics such conditional dynam-ics are called quantum trajectories.^{23[,25](#page-19-33)} Let us suppose that at time $t = t_k$, the occupation of the dot is zero and the jump process $dN_L(t)$ occurs at $t = t_k + dt_k$. The dot then becomes occupied while the state of the oscillator changes according to^{28} to^{28} to^{28}

FIG. 7. (Color online) QO toolbox simulation for shuttling condition (bold lines), compared with the semiclassical simulation (thin lines). Parameters are γ_L $=\gamma_R=1, \quad \nu=1, \quad \eta=0.3, \quad \chi=1, \quad \kappa$ =0.05. We set the initial condition as X_0 =4.1 and Y_0 =0 to start the evolution close to the limit cycle. (a) Evolution of average values for position (solid lines) and momentum (dashed lines), electron number, current in the source and the energy of the oscillator; (b) Limit cycle behavior in 3D.

$$
|\psi(t_k)\rangle \xrightarrow{dN_L} |\psi_L(t_k + dt_k)\rangle = \frac{1}{\sqrt{p_L(\mu, t_k)}} e^{-\mu \hat{x}/2} |\psi(t_k)\rangle,
$$
\n(45)

where $p_L(\mu, t_k) = \langle \psi(t_k) | e^{-\mu \hat{x}} | \psi(t_k) \rangle$ and we have defined μ =2/ λ . With these definitions we see that $\mathcal{E}[dN_L(t_k)]$ $= \gamma_L p_L(\mu, t_k) dt.$

We can develop some useful insight into what this state transformation means in the case that $|\psi(t_k)\rangle$ is a Gaussian with mean position of \bar{x}_k and variance σ_k . In this Gaussian case we have

$$
p_L(\mu, t_k) = e^{-\mu \bar{x}_k} \sum_{m=0}^{\infty} \frac{(\sigma_k \mu^2)^m}{(2m)!},
$$
 (46)

where $(2m)! = 2.4.6, \ldots, 2m$. After the jump process the mean position changes to

$$
\langle \psi_L | \hat{x} | \psi_L \rangle = \bar{x}_k - 2 \sigma_k / \lambda. \tag{47}
$$

This equation applies equally well to jumps to the right *dNR* with a change in the sign of λ . Thus we see that if there is jump due to dN_L , on average the conditional state moves to state with a mean *closer* to the source, while if a jump occurs to the right, dN_R , the conditional state changes to a state with

FIG. 8. (Color online) Plot of the difference between the factorized and unfactorized moments $\langle (a+a^{\dagger}) \rangle \langle c^{\dagger} c \rangle - \langle (a+a^{\dagger}) c^{\dagger} c \rangle$ in Fig. [7.](#page-9-0)

a mean position *closer* to the drain. Of course it is unlikely that the state of the oscillator is ever Gaussian. However, we expect that a jump to the left (right) will still lead to a conditional state with a mean value closer to the left (right) lead. In all of the conditional dynamics the occupation of the dot is either exactly zero or one.

The Quantum Optics Toolbox enables a direct computation of the conditional dynamics of the operator moments by implementing a so called "jump unraveling" of the master equation. First we plot a sample trajectory for a slow electron jump rate $\gamma_L = 0.1$ to see the effect of electron jump on the evolution picture of the system. A random jump of electrons from the source to the island (Fig. [11](#page-11-0)) according to rate γ_L ,

FIG. 10. A schematic illustration of the two potential surfaces connected by Poisson jumps.

 γ_R was introduced. The dynamics of the shuttle as a position transducer, as predicted in Sec. IV, can be seen in the conditional averages of the displacement. The variable η controls the amount of displacement of the island when an electron jumps on and off onto the island. Larger value of η caused a larger displacement kick when a jump occurs. During the time when the electron is on the island, the phonon number of the oscillator oscillates with a similar behavior to the oscillation of the position.

The single trajectory for the shuttle case with the same parameter in Fig. [7](#page-9-0) can be seen in Fig. [12.](#page-11-1) The electrons mostly jump onto the island from the source when it is closer to the source and jump off when closer to the drain. At the jump, the island gets a slight displacement kick towards the source when jumping on and towards the drain when jumping off. However, this does not stop the shuttling motion of the island and does not repel it to the opposite direction as suggested earlier by Nord *et al.*[36](#page-19-31) It can also be seen that when the electron manages to jump onto the island when island is still close to the drain, it is more probable for the electron to jump off straight away.

The conditional dynamics of the system just described corresponds to an experiment in which number of electrons

FIG. 9. (Color online) Plot of the difference between the factorized and unfactorized moments for various η with $\gamma_L = \gamma_R = 1$, χ $=0.5, \; \kappa = 0.05.$

FIG. 11. (Color online) Plot of a single trajectory showing the dynamics of the jump and the result in the phonon number. Parameters are $\gamma_L = \gamma_R = 0.1$, $\nu = 1$, $\eta = 0.3$, $\chi = 1$, $\kappa = 0.05$.

on island is monitored continuously in time. As we can see, the behavior of the conditional dynamics differs from the behavior of the ensemble average. However, averaging over many different realization of the trajectories as shown in Fig. [12](#page-11-1) would lead to a closer and closer approximation of the ensemble average behavior in Fig. [7.](#page-9-0)

B. Strongly damped regime

There are two ways of damping the shuttle into the fixed point regime. One is to damp the motion of the shuttle itself by introducing a large mechanical damping κ . Alternatively we can damp the oscillation of the electron occupation number in the island. This happens when the rates of the electron jump γ_L , γ_R are large compared to the natural frequency of the island vibration. The fast electron jumps act as an internal damping to the shuttle. Within this regime the electron

FIG. 12. (Color online) Plot of a single trajectory showing the dynamics of the jump when $\gamma_L = \gamma_R = 1$, $\nu = 1$, $\eta = 0.3$, $\chi = 1$, $\kappa = 0.05$.

number expectation $\langle c^{\dagger} c \rangle$ monotonically approaches 0.5 when $\gamma_L = \gamma_R$.

When the bare electron tunneling rates are very large compared to other frequency scales in the problem, we may assume the dot approaches its steady state for bare tunneling quickly as compared to the typical time scale of the oscillator. In this case, $\rho(t) = \rho_d^{\text{st}} \times \rho_o(t)$. The bare ρ_d^{st} can be substituted into the density matrix of the total master equation and then be traced out with respect to the dot degrees of freedom to get an effective master equation which involves only the reduced density matrix of the oscillator. This effective master equation can be calculated from the reduced density matrix, from Eq. (11) (11) (11) .

At the strongly damped regime when the oscillation of the shuttle is reasonably small, it is safe to assume that the variation in the tunnel rate due to the shuttle's position is sufficiently represented by a low order expansion of η . Thus we can expand the expression to second order in η : $e^{\eta \hat{X}} = 1$ $+\eta \hat{X} + (\eta \hat{X})^2 / (2!) + \cdots$. We can then rewrite the zero temperature full master equation as

$$
\dot{\rho} = -i\nu[a^{\dagger}a,\rho] + 2i\chi[\hat{X}\bar{n},\rho] + 2\gamma_L(1-\bar{n})\,\eta^2(\hat{X},[\hat{X},\rho])
$$

$$
+ 2\gamma_R\bar{n}\,\eta^2(\hat{X},[\hat{X},\rho]) + \kappa(\bar{n}_p + 1)\mathcal{D}[a]\rho + \kappa\bar{n}_p\mathcal{D}[a^{\dagger}]\rho,
$$
\n(48)

with $\bar{n} = \gamma_L / \gamma_L + \gamma_R$. The following moments can thus be derived from Eq. (48) (48) (48) :

$$
\frac{d\langle a^{\dagger}a\rangle}{dt} = 2\chi\bar{n}\langle \hat{Y}\rangle - 4\gamma_L(1-\bar{n})\eta^2 - 4\gamma_R\bar{n}\eta^2 + \kappa\bar{n} - \kappa\langle a^{\dagger}a\rangle,\tag{49}
$$

$$
\frac{d\langle\hat{X}\rangle}{dt} = \nu\langle\hat{Y}\rangle - \frac{\kappa}{2}\langle\hat{X}\rangle,\tag{50}
$$

FIG. 13. (Color online) Average evolution of the shuttle with a large γ_L and γ_R . Here we have chosen $\gamma_L = \gamma_R = 10$, $\eta = 0.1$, χ $= 0.1, \kappa = 0.05, X_0 = 0.5, Y_0 = 0$ for both quantum simulation with *N* = 25 (thick lines) and semiclassical solution (thin lines).

$$
\frac{d\langle \hat{Y} \rangle}{dt} = -\nu \langle \hat{X} \rangle + \chi \bar{n} - \frac{\kappa}{2} \langle \hat{Y} \rangle.
$$
 (51)

The moments $\langle \hat{X} \rangle$ and $\langle \hat{Y} \rangle$ form a closed system of differential equation which can readily be solved.

$$
\langle \hat{X} \rangle = e^{-(\kappa/2)t} [(X_0 - X_*) \cos(\nu t) + (Y_0 - Y_*) \sin(\nu t)] + X_*,
$$
\n(52)\n
$$
\langle \hat{Y} \rangle = e^{-(\kappa/2)t} [- (X_0 - X_*) \sin(\nu t) + (Y_0 - Y_*) \cos(\nu t)] + Y_*,
$$
\n(53)

where again X_* and Y_* is simply the displacement in the equilibrium such as given in Eqs. (32) (32) (32) and (33) (33) (33) with $n_* = \overline{n}$. X_0 and Y_0 are the initial conditions of *X* and *Y*, respectively. The analytic expressions of Eqs. (52) (52) (52) and (53) (53) (53) are useful for checking the solution of the master equation given by Matlab, to ensure that the truncation in the phonon number is adequate.

The shuttle oscillation is damped to the new displaced position of *X** which agrees to the obtained result previously. When $\gamma_L = \gamma_R = \gamma$, we have $n_* = \overline{n} = \frac{1}{2}$ in the regime when the tunneling rates are very large compared to other frequency scales (especially when η is relatively small). In this case, the oscillatory behavior of Eqs. (52) (52) (52) and (53) (53) (53) do not depend on the actual values of the tunneling rates γ . It can also be deduced that the decay rate of the oscillation envelope is $e^{-\kappa t/2}$. In this regime, the result of the analytical expressions matches the quantum simulation quite well (see Fig. [13](#page-11-3)).

C. Coexistence regime

As discussed in Sec. III, we can also have a regime in which the behavior of the shuttle depends on its initial condition. The system will either be attracted to the limit cycle and thus be in the shuttle regime or be attracted to the fixed point and be in the tunneling regime depending on its initial condition within the correct parameters where the subcritical bifurcation occurs. Following previous authors, 19 we call this the "coexistence regime."

Semiclassically this can be seen when we plot the average evolution of the shuttle. Depending on the initial conditions, the shuttle will either be attracted to the fixed point position or undergoes the stable limit cycle oscillation. When we start the initial condition at a position before the unstable limit cycle appears, the shuttle motion will be attracted to the fixed point. However, if we pick a point outside this unstable limit cycle the shuttle will be attracted to the stable limit cycle. We show this in Fig. [14,](#page-12-2) where the evolution starts close to the inner unstable limit cycle and proceed to find the outer stable limit cycle.

The quantum average calculation in this regime, however, does not show the subcritical bifurcation since averaging over the noise in the system dampens this effect. This can be seen in the evolution of the single trajectory which is captured to the fixed point position at random times. A sample of trajectories each from different initial conditions were plotted in Figs. [15](#page-12-3) and [16.](#page-13-0)

FIG. 14. (Color online) Semiclassical limit cycle of the shuttle in the coexistence regime. Here we have chosen $\gamma_L = 0.03$, $\gamma_R = 1$, η =0.3, χ =1, κ =0.05, X_0 =2.2, and Y_0 =0. The evolution starts close to the unstable limit cycle and then moves toward the stable limit cycle.

D. Finite temperature

We can easily extend these calculations to the finite temperature case by including the Fermi factors f_L and f_R which were previously set to 1 and 0 for the zero temperature case. At this condition the Fermi function will vary significantly following the choice of the bias voltage.

Within the shuttle regime, the effect of finite temperature and varying bias is plotted in Fig. [17.](#page-13-1) Comparing this with previous result for the zero temperature (Fig. 7) there is a suppression of the electron number oscillation. The shuttle still oscillates as it were in the shuttle regime however with a smaller amplitude. There is also a significant difference between the quantum and the semiclassical simulation for the electron number occupation which resulted in a difference in the current in each of the leads.

FIG. 15. (Color online) Single trajectory of the shuttle from an initial position before the unstable limit cycle appears. Here we have chosen $\gamma_L = 0.01$, $\gamma_R = 1$, $\eta = 0.3$, $\chi = 1$, $\kappa = 0.05$, $X_0 = 1.2$, and $Y_0 = 0$.

FIG. 16. (Color online) Single trajectory of the shuttle from an initial position on the stable outer limit cycle and after the unstable limit cycle appears. Here we have chosen $\gamma_L = 0.01, \gamma_R = 1, \eta$ $= 0.3$, $\chi = 1$, $\kappa = 0.05$, $X_0 = 5$, $Y_0 = 0$.

A change of behavior of the shuttle can occur if we lowered the f_L value much further such that the critical value χ_h as given in Eq. (35) (35) (35) (but a version with Fermi factors included) is higher than our chosen value of χ . At this case the shuttle is likely to be driven back to the subcritical regime in which it will be driven to the stationary points when we start the simulation the same initial position.

V. NOISE CALCULATION

In surface gated two-dimensional electron gas structures some recent experiments monitor the charging state of the dot via conductance in a quantum point contact.³⁹ However, such techniques cannot easily be adapted for a nanoelectromechanical system. In experiments involving tunneling through a double barrier quantum dot structure the simplest thing to measure is the source-drain current. In the QEMS experiments of Park *et al.*[6](#page-19-6) and also of Erbe *et al.*, the source drain current carried signatures of the vibration of the nanoelectromechanical component. In this section we calculate, using the Quantum Optics Toolbox, the current noise spectrum and show that it indicates the transition between the fixed point and the shuttling regime.

The current seen in the external circuit, when electrons tunnel on and off the dot, only indirectly reflects the quantum nature of the tunneling process. Tunneling causes a local departure from equilibrium in the source and drain reservoirs that is restored through a fast irreversible process in which small increments of charge are exchanged with the external circuit. While tunneling obviously involves a change of charge in units of $\pm e$, the increments of charge drawn by the external circuit are continuous quantities determined by the overall capacitance and resistance of the circuit. The current responds as a classical stochastic process conditioned on the quantum stochastic processes involved in the tunneling. In many ways this is analogous to the response of a photoelectron detector to photons.

The connection between the quantum stochastic process of tunneling and the current observed in the external circuit

FIG. 17. (Color online) Average evolution of the shuttle with finite temperature. Here we have chosen electronic bath temperature T_{el} =1.5 K with $\gamma_L = \gamma_R = 1$, $\eta = 0.3$, $\chi = 1$, $\kappa = 0.05$, $X_0 = 4.1$, $Y_0 = 0$, at ω_I =3 and *V*_{bias}=6.07 such that f_L =0.8 and f_R =0 for both quantum simulation with $N=47$ (thick lines) and semiclassical approximation (thin lines).

is given by the Ramo-Shockley theorem and is a linear combination of the two Poisson processes defined in Eqs. (14) (14) (14) and ([15](#page-3-4)). The noise spectrum of such a current involves moments of both the tunneling processes, and correlations between them. In Sun *et al.*, [40](#page-19-37) one can find a detailed example of how such correlations are determined by the corresponding master equation for the quantum dot system.

Recently Novotny *et al.*[17](#page-19-17) and Flindt *et al.*[18](#page-19-18) have calculated a noise spectrum for the shuttle system defined in terms of the fluctuating electron number accumulating in the drain reservoir. Here we adopt a different (but equivalent) approach based on the framework of quantum trajectories. In this section we calculate, using quantum trajectory methods, the stationary current noise spectrum in the *drain* current alone as this suffices to illustrate how the current noise spectrum reflects the transition from fixed point to shuttling. The total current shows the same features but has a different noise background.

The stationary two-time correlation function quantifies the fluctuations in the observed current and is defined by 31

$$
G(t,\tau)|_{t\to\infty} = \frac{e}{2}i_{\infty}\delta(\tau)
$$

+
$$
\{E[I(t)I(t+\tau)] - E[I(t)]E[I(t+\tau)]\}_{t\to\infty}^{\tau\neq 0}.
$$

The first term is responsible for shot noise in the current, while the second term quantifies noise correlations. We now show how the second term can be defined in terms of the stationary state of the quantum dot and oscillator themselves.

Let $\rho(t)$ be the density operator representing the dot and oscillator at time *t*. What is the conditional probability that, given an electron tunnels into the drain from the dot between *t* and *t*+*dt*, and another similar tunneling event takes place at a time τ later (with no regard for what tunneling events have occurred in the mean time)? If an electron tunnels from the

FIG. 18. (Color online) Plot of spectrum in the left junction with various η , setting $\gamma_L = \gamma_R = 1$, χ $=0.5, \; \kappa = 0.05.$

dot into the drain at time *t*, the conditional state of the dot and oscillator (unnormalized), conditioned on this event is given $by^{30,31}$ $by^{30,31}$ $by^{30,31}$

$$
\tilde{\rho}^{(1)}(t) = \gamma_R e^{\hat{x}/\lambda} c \rho(t) c^{\dagger} e^{\hat{x}/\lambda}.
$$
 (54)

Given this state, the probability that another tunneling event takes place a time τ later is

$$
\gamma_L \text{tr}\{e^{2\hat{x}/\lambda}c^{\dagger}c e^{\mathcal{L}}\textcolor{black}{T} \textcolor{black}{\widetilde{\rho}}^{(1)}(t)\} = \gamma_L^2 \text{tr}\{e^{2\hat{x}/\lambda}c^{\dagger}c e^{\mathcal{L}}\textcolor{black}{T} e^{\hat{x}/\lambda}c \rho(t) c^{\dagger} e^{\hat{x}/\lambda}\}\},
$$

where formally we have represented the irreversible dynamics from time *t* to $t + \tau$ as the propagator $e^{\mathcal{L}\tau}$. Let us now

assume that the first conditioning event takes place at a time *t* long after any information about the initial state of the quantum dot has decayed away. That is to say the first conditioning event occurs when the dot has settled into the stationary state, $\rho_{\infty} = \lim_{t \to \infty} \rho(t)$. The stationary two-time correlation function for the current through the right junction into the drain is then defined, up to a term due to shot noise, by

$$
G(\tau) = E\{I_R(t)I_R(t+\tau) - [I_R(\infty)]^2\}_{t \to \infty}^{\tau > 0}
$$
 (55)

FIG. 19. (Color online) Plot of spectrum in the left junction with various γ_L , setting $\gamma_R = \gamma_L$, $\eta = 0.3$, $\chi=0.5$, $\kappa=0.05$.

$$
= \gamma_R^2 \{ \text{tr}(e^{2\hat{x}/\lambda} c^{\dagger} c e^{\mathcal{L}} \mathcal{T} [e^{\hat{x}/\lambda} c \rho_{\infty} c^{\dagger} e^{\hat{x}/\lambda}] \} - \text{tr}(e^{2x/\lambda} c^{\dagger} c \rho_{\infty})^2 \}. \tag{56}
$$

In terms of the dimensionless position operator \hat{X} , the noise in the two-time correlation functions becomes

$$
G(\tau) = \gamma_R^2 \{ \text{tr} \big[e^{4\eta \hat{X}_C \dagger} c e^{\mathcal{L}\tau} (e^{2\eta \hat{X}_C} \rho_\infty c^\dagger e^{2\eta \hat{X}}) \big] - \text{tr} \big(e^{4\eta \hat{X}_C \dagger} c \rho_\infty \big)^2 \},
$$

where $e^{\mathcal{L}\tau}$ is the master equation evolution.

The noise power spectrum of the current is given by

$$
S(\omega) = 2 \int_0^\infty G(\tau) (e^{i\omega \tau} + e^{-i\omega \tau}) d\tau.
$$
 (57)

This noise spectrum can be directly calculated using the Quantum Optics Toolbox by first calculating the steady state solution ρ_{∞} and setting $e^{2\pi \hat{X}} c \rho_{\infty} c^{\dagger} e^{2\pi \hat{X}}$ as an initial condition for the master equation evolution. Then we can calculate the expectation value of the operator $c^{\dagger}ce^{4\eta \hat{X}}$ in the state evolved, according to the master equation, from this initial condition. It is important to note that the master equation does indeed have a steady state even in that parameter regime in which the semiclassical dynamics would imply a limit cycle. This is because quantum fluctuations cause a kind of phase diffusion around the limit cycle. These quantum fluctuations are precisely the random switchings observed in the single quantum trajectory shown in Fig. [12.](#page-11-1) In fact as shown in Ref. [15](#page-19-15) the Wigner function of the steady state has support on the entire limit cycle. The relation between our method and the method used by Novotny *et al.*[17](#page-19-17) to calculate the zero frequency noise spectrum $S(0)$ is explained in the Appendix.

The example of the noise spectra for various η is shown in Fig. [18.](#page-14-0) The transition between the tunneling regime and the shuttling regime is clearly evident here (we have subtracted off the shot noise background). Setting $\eta=0$, $\chi=0$ we arrived back at the known spectrum for the drain current in a double barrier device⁴⁰ with a single dip at zero frequency. At this condition, the current rises and reaches a steady state due to tunneling of the electron.

As the values of η and χ (or γ_L) are increased, the frequency spectra develop sidebands which correspond to the frequency of the oscillator (Fig. [18](#page-14-0)). Within the weakly coupled QEMS, this appearance of sideband is also predicted by Wabnig *et al.*^{[41](#page-19-39)} and Armour.⁴²

As the system approaches the shuttling regime, the frequency spectra pick up additional noise peaks at higher frequencies close to a multiple of the oscillator frequency. This is a signature of the limit cycle formation. On the limit cycle, the frequency is shifted from the base oscillation frequency ω =1.055 ν . This is also given by the imaginary part of the eigenvalues of the linearized matrix expressed by μ $=\sqrt{A_*\kappa+1+(\kappa/2)^2}$. This observation agrees with the predicted slight renormalization of the frequency by Flindt *et al.*[18](#page-19-18)

The effect of the tunnel rate on the behavior of the shuttle can be seen from the plot of noise spectrum across various γ_L which is plotted in Fig. [19.](#page-14-1) Here as we varied γ_L along with γ_R , we swept across the three regimes. First we start

FIG. 20. Plot of noise spectrum in the left junction with various γ_L , setting $\gamma_R = \gamma_L$, $\eta = 0.3$, $\chi = 0.5$, $\kappa = 0.05$. (a) Transition from fixed point $(\gamma_L = 0.003, 0.005)$ to coexistence regime $(\gamma_L = 0.01)$. (b) Transition from coexistence regime $(\gamma_L=0.01)$ to shuttling regime $(\gamma_L = 0.03, 0.05)$.

from the fixed point regime $(\gamma_L=0.003,0.005)$ marked by a dip at zero frequency noise [Fig. $20(a)$ $20(a)$]. Then the transition to coexistence regime occurs around γ_L =0.01. This is marked by the appearance of both zero frequency noise dip and peaks at integer multiple of the oscillator frequency. This coexistence regime exists until around $\gamma_L = 0.03$ where the shuttling behavior begins [Fig. $20(b)$ $20(b)$]. This shuttling regime continues in Fig. [19](#page-14-1) up until around $\gamma_L = 1.3$ where the positive zero frequency noise starts to appear and the system enters the coexistence regime. The system settles into the fixed point regime once more at high γ_L since the high tunnel rates provide an intrinsic damping to the system. 29 The peak in the zero frequency spectrum occurs due to the large tunnel rates which produce rapidly fluctuating current around the steady state value.

In summary, the tunneling condition can produce either a single dip or a single peak at the noise spectrum depending on the tunnel rates, which determine the vibrational fre-

FIG. 21. (Color online) Plot of steady state current in the right junction and the zero frequency Fano factor for various damping κ , setting $\gamma_R = \gamma_L$, $\chi = 0.5x_0$ while η is given in units of x_0^{-1} .

quency of the island around the fixed point. The shuttling regime is marked by the appearance of the peaks at integer multiples of the oscillator frequency while the coexistence regime is marked by the appearance of the features from both the tunneling regime and the shuttling regime; that is the appearance of dip in the zero frequency at low tunnel rates and also peaks at integer multiples of the frequency.

We can also investigate the Fano factor, which is given by

$$
F(\omega) = \frac{S(\omega)}{2eI(\omega)}.\tag{58}
$$

The Fano factor of the noise at zero frequency is plotted in Fig. [21.](#page-16-0) Here we plot the steady state current in the drain and its corresponding Fano factor at zero frequency using the values used by Novotny *et al.*[17](#page-19-17) to compare the results. We plot each of the curves against $\kappa/2$ as our damping variable was defined approximately twice the value used by Novotny *et al.* Here we set $\gamma_R = \gamma_L$, $\chi = 0.5x_0$ and plot for $\eta = 0.5/x_0$ and $\eta = 1/x_0$, where $x_0 = \sqrt{\hbar/mv}$.

At regions where the damping is large, the steady state current plot agrees well with the result obtained by Novotny *et al.* However, contrary to the plot given by Novotny *et al.*, [17](#page-19-17) we do not find the maximum current to reach the magic number 0.16. However, at small values of oscillator damping, the mean steady state phonon number is large which causes difficulties for our numerical scheme. Our approach is to numerically solves the steady state master equation which necessitates a truncation of the oscillator basis. Truncating at too low a value leads to invalid results, while extending the truncation level leads to impractically long run times.

For a clearer picture, we might also plot the Fano factor at zero frequency ($\omega=0$), the first oscillator frequency ($\omega=\nu$), and twice the oscillator frequency $(\omega = 2\nu)$ for various γ_L , with the corresponding values we used for Fig. 19 (see Fig.

[22](#page-16-1)). Here we can see that the Fano factor at the oscillator frequency starts to appear at $\gamma_L = 0.01$ which is the start of the coexistence regime and increases at $\gamma_L = 0.5$, where the shuttling begins. Shuttling continues until $\gamma_L \approx 1$ which then changes to coexistence and back into tunneling regime when all the Fano factors coincide at high γ_L .

Our result agrees with the semiclassical prediction of Isacsson¹⁰ which indicates that the shuttle system can exhibit limit cycle behavior. Although we do not have the gate voltage dependence here, we observe similar behavior of the system which reduces to one fixed point regime when damping (or in our case the tunnel rate γ_L) is increased. Interest-

FIG. 22. (Color online) Plot of Fano factor at zero frequency $(\omega=0)$, the first oscillator frequency $(\omega=\nu)$ and twice the oscillator frequency $(\omega=2\nu)$ for various γ_L , setting $\gamma_R = \gamma_L$, $\eta = 0.3$, $\chi = 0.5$, κ =0.05.

ingly for $\gamma_L < \nu$, the quantum steady state current calculated is greater than the semiclassical steady state current. The two steady state currents agree when $\gamma_L \approx \nu$. When $\gamma_L > \nu$, the quantum steady state current now becomes less than the semiclassical prediction. When η is not small, the oscillator dynamics develops strong anharmonicity and we expect the semiclassical and quantum dynamics to differ. This limit requires further study.

A similar feature of the noise is found by Armour⁴² in a system consisting of a SET that is coupled to a nanomechanical resonator. Although this is a different system from the shuttle system, the classical noise spectrum in this system also shows the dependence of the current on the position of the nanomechanical resonator.

VI. CONCLUSION

The dynamics of the shuttle system has been investigated via both the semiclassical and the full quantum master equation treatment. The latter reveals subtle properties of the dynamics which was not found using the semiclassical treatment. The master equation is solved numerically using the Quantum Optics Toolbox enabling a detailed comparison of the semiclassical dynamics with the quantum ensemble averages. For the first time in the study of the quantum shuttle we compute the moments for the quantum state conditioned on a particular history of tunneling events. This is called a quantum trajectory and it reflects what can be observed experimentally by monitoring the electron on the island.

The conditional dynamics differs from the behavior of the ensemble average, and gives new insight into the shuttling dynamics. In the shuttling regime, the ensemble average dynamics of the electron occupation number is a smoothed square wave that slowly decays to a steady state value of one half. Given that the occupation number of the dot is either zero or unity this ensemble averaged behavior may seem unexpected. However, looking at the occupation number in a single conditional state (see Fig. 11) indicates what is going on. A single quantum trajectory shows that the average occupation number is indeed either zero or unity and in the shuttling regime behaves similar to a square wave for short times but, at random times, suffers a phase jump. The ensemble average of many such trajectories with phase jumps at random times leads to the observed ensemble average dynamics as computed from the master equation. These random phase jumps ultimately lead to a steady state density operator for the system that, in the Wigner representation, is diffused around the limit cycle, as noted by Novotny *et al.*[15](#page-19-15)

The shuttle dynamics was investigated in two regimes: the fixed point and the shuttling regime. In the fixed point regime, the shuttle is damped to a new displaced position. We have shown that there is a strong relation between the current and the fixed point of the position. This relationship is linear when the tunnel length is large (η small). Thus it is possible to use the shuttle in a position transducer scenario. In this regime, the semiclassical treatment is shown to be accurately sufficient to describe the dynamics.

We provide the condition in which the shuttling regime will appear from the system by identifying the appearance of limit cycle in the phase space of the shuttle. A careful analysis of the nonlinear dynamics using center manifold method indicates that when $\gamma_L = \gamma_R$, the limit cycle forms through a supercritical pitchfork bifurcation. However, when $\gamma_L \neq \gamma_R$ there is a region of parameter space in which the bifurcation can be subcritical, and for which hysteresis is possible. Adjusting the damping κ with respect to these parameters will cause the shuttle to be sufficiently damped and thus allow the shuttling to take place. The shuttling regime also appears when the rate of the electron tunneling is close to the oscillator frequency. The shuttling regime corresponds to the continuous oscillation of the electron number and results in additional peaks at multiples of the limit cycle frequency in the noise spectra. This is destroyed when κ is too large or when a large electron jump γ_L , γ_R are introduced to the system. Both of these conditions will damp the shuttle into the displaced equilibrium position. The quantum shuttle thus provides a fascinating example of a quantum stochastic system in which electron transport is coupled to mechanical motion. In future studies we will investigate how such a system can be configured for sensitive force detection.

ACKNOWLEDGMENTS

H.S.G. is grateful to the Centre for Quantum Computer Technology at the University of Queensland for their hospitality during his visit. H.S.G. would also like to acknowledge the support from the National Science Council, Taiwan under Contract No. NSC 94-2112-M-002-028, and support from the focus group program of the National Center for Theoretical Sciences, Taiwan under Contract No. NSC 94-2119-M-002-001. G.J.M. acknowledges the support of the Australian Research Council.

APPENDIX

In this appendix we wish to compare the approach to calculating the noise power spectrum used by Novotny *et al.*[17](#page-19-17) and our approach. Novotny *et al.* first define the probability that n electrons tunnel into the drain (right) lead up to time t as $P_n(t)$. Then they define the (stationary) mean current in the drain and zero frequency shot noise of the current in the drain as

$$
I = e \frac{d}{dt} \sum_{n} n P_n(t) \Big|_{t \to \infty} = e \sum_{n} n P_n(t) \Big|_{t \to \infty}, \quad \text{(A1)}
$$

$$
S(0) = 2e^2 \frac{d}{dt} \left[\sum_n n^2 P_n(t) - \left(\sum_n n P_n(t) \right)^2 \right] \Big|_{t \to \infty} .
$$
 (A2)

Novotny *et al.* then subsequently show that

$$
I = e \gamma_R \text{tr}_{\text{osc}}[e^{2x/\lambda} \rho_{11}(t)]|_{t \to \infty}.
$$
 (A3)

To make the connection to our formalism we note that the number of electrons $n(t)$ (a stochastic process) that have tunneled into the drain from $t=0$ to a later time t is simply the accumulation of the number of jump processes to the right

$$
n(t) = \int_0^t dN_R(t').
$$
 (A4)

The mean value of this stochastic process is

$$
\mathcal{E}[n(t)] = \int_0^t \mathcal{E}[dN_R(t')] \tag{A5}
$$

$$
= \int_0^t \gamma_R \text{tr}[e^{2x/\lambda} c^\dagger c \rho(t')] dt', \quad \text{(A6)}
$$

where we have used Eq. (15) (15) (15) . Thus the electric current through the right junction to the drain is

$$
I_R = e \frac{d}{dt} \mathcal{E}(n(t)) \Big|_{t \to \infty} = e \gamma_R \text{tr}(e^{2x/\lambda} c^\dagger c \rho_\infty) \tag{A7}
$$

and doing the partial trace over the dot occupation we see that this average is in fact identical to I as in Eq. $(A3)$ $(A3)$ $(A3)$ when the steady state limit is taken.

Turning to the zero frequency noise $S(0)$ we see that the definition of Novotny *et al.* may be paraphrased as saying that the zero frequency current noise in the drain is proportional to the rate of change of the variance in the number of electrons that have tunneled to the right, in the steady state limit. Using Eq. $(A4)$ $(A4)$ $(A4)$, we see that this variance is

$$
\mathcal{V}[n(t)] = \mathcal{E}[n(t)^{2}] - \mathcal{E}[n(t)]^{2}.
$$
 (A8)

Taking the first quadratic moment

$$
\mathcal{E}[n(t)]^2 = \int_0^t \int_0^t \mathcal{E}[dN_R(t_1)dN_R(t_2)].
$$
 (A9)

We need to be careful here as on the line $t_1 = t_2$, $dN(t_1)dN(t_2) = dN(t_1)$. Perhaps the best way to proceed is to discretize the interval $(0, t)$ in steps of size τ . Then define $t_k = k\tau$ and $\delta N_k = dN(t_k)$ and the end point $t = n\tau$. The double integral then reduces to

$$
\begin{split} \int_0^t \int_0^t dN_R(t_1) dN_R(t_2) &\approx \sum_{k=0}^n \sum_{l=0}^n \delta N_n \delta N_l \\ &= \sum_{k=0}^n (\delta N_k)^2 + 2 \sum_{l < k}^n \delta N_k \delta N_l \\ &\rightarrow \int_0^t dN(t_1) + 2 \int_0^t \int_0^{t_1} dN(t_1) dN(t_2). \end{split}
$$

So

$$
\frac{d}{dt}\mathcal{E}[n(t)^{2}] = \mathcal{E}\left(\frac{dN(t)}{dt}\right) + \int_{0}^{t} \mathcal{E}\left(\frac{dN_{R}(t)}{dt}dN_{R}(t')\right)
$$
\n(A10)

$$
= \gamma_R \langle e^{2x/\lambda} c^{\dagger} c \rangle + \int_0^t \mathcal{E} \bigg(\frac{dN_R(t)}{dt} dN_R(t') \bigg). \tag{A11}
$$

Now

$$
\int_0^t \mathcal{E}[dN_R(t)dN_R(t')] \n= \int_0^t \Pr[dN(t') = 1] \Pr[dN_R(t) = 1|dN_R(t') = 1]
$$
\n(A12)

$$
= \gamma_R^2 \int_0^t \text{tr}\{e^{2\hat{x}/\lambda} c^\dagger c e^{\mathcal{L}(t-t')} \times [e^{\hat{x}/\lambda} c \rho(t') c^\dagger e^{\hat{x}/\lambda}]\} dt' dt,
$$
\n(A13)

where we have used the fact that the increments $dN_R(t)$ are either 0 or 1 to write the average in terms of the conditional probability $Pr[dN_R(t)=1 | dN_R(t')=1]$ that given a jump to the right at time t' there is another jump to the right a time *t*−*t*' later. This probability is found by taking the quantum state of the system at time t' and then finding the conditional state that results when a jump to the right takes place at time *t*', that is $c\rho(t')c^{\dagger}$, evolving this forward for a time *t*−*t*' according to the master equation, then computing the probability for the state at that later time to produce another jump to the right at time *t*. For further discussion on this way of thinking about conditional quantum states see, for example, Refs. [26](#page-19-41) and [31.](#page-19-38)

The second term in Eq. $(A2)$ $(A2)$ $(A2)$ may be evaluated by noting that

$$
\frac{d}{dt} \left(\sum_{n} n P_n(t) \right)^2 = 2 \mathcal{E}[n(t)] \frac{d}{dt} \mathcal{E}[n(t)] \tag{A14}
$$

$$
=2\gamma_R^2 \text{tr}[e^{2x/\lambda}c^\dagger c\rho(t)]
$$

$$
\times \int_0^t \text{tr}[e^{2x/\lambda}c^\dagger c\rho(t')]dt'. \qquad (A15)
$$

We can now take the stationary limit

$$
\lim_{t \to \infty} \frac{d}{dt} \{ \mathcal{E}[n(t)^2] - \mathcal{E}[n(t)]^2 \}
$$
\n(A16)

$$
= \gamma_R \langle e^{2\hat{x}/\lambda} c^{\dagger} c \rangle_{\infty} + 2 \gamma_R^2 \int_0^{\infty} \text{tr} [e^{2\hat{x}/\lambda} c^{\dagger} c e^{\mathcal{L}\tau} (e^{\hat{x}/\lambda} c \rho_{\infty} c^{\dagger} e^{\hat{x}/\lambda})] d\tau
$$

$$
- 2 \gamma_R^2 \text{tr} (e^{2x/\lambda} c^{\dagger} c \rho_{\infty}) \int_0^{\infty} \text{tr} (e^{2x/\lambda} c^{\dagger} c \rho_{\infty}) dt' \tag{A17}
$$

$$
= \gamma_R \langle e^{2\hat{x}/\lambda} c^{\dagger} c \rangle_{\infty} + 2 \gamma_R^2 \int_0^{\infty} d\tau \{ \text{tr} [e^{2\hat{x}/\lambda} c^{\dagger} c e^{\mathcal{L}\tau} (e^{\hat{x}/\lambda} c \rho_{\infty} c^{\dagger} e^{\hat{x}/\lambda})]
$$

$$
- \text{tr} (e^{2x/\lambda} c^{\dagger} c \rho_{\infty})^2 \}
$$
(A18)

$$
=\gamma_R \langle e^{2\hat{x}/\lambda} c^{\dagger} c \rangle_{\infty} + 2 \int_0^{\infty} d\tau G_d(\tau), \tag{A19}
$$

where we have defined the drain two-time correlation func-

tion $G_d(\tau)$ corresponding to the drain correlation function given in Eq. (56) (56) (56) . Now the second term here is just our expression for the noise power spectrum evaluated at zero frequency. Therefore, we have a relation between the zero

frequency noise function $S(0)$ as defined by Novotny *et al.*, which is, up to an additive constant due to shot noise, the same as our expression for zero frequency noise power spectrum.

- *Electronic address: wahyu@physics.uq.edu.au
- † Electronic address: goan@phys.ntu.edu.tw
- ¹R. G. Knobel and A. N. Cleland, Nature (London) 424, 291 $(2003).$
- 2M. D. LaHaye, O. Buu, B. Camarota, and K. Schwab, Science 304, 74 (2004).
- ³K. L. Ekinci, X. M. H. Huang, and M. L. Roukes, Appl. Phys. Lett. **84**, 4469 (2004).
- 4L. Y. Gorelik, A. Isacsson, M. V. Voinova, B. Kasemo, R. I. Shekhter, and M. Jonson, Phys. Rev. Lett. 80, 4526 (1998).
- 5R. I. Shekhter, Y. Galperin, L. Gorelik, A. Isacsson, and M. Jonson, J. Phys.: Condens. Matter 15, R441 (2003).
- 6H. Park, J. Park, A. K. Lim, E. H. Anderson, A. P. Allvisator, and P. L. McEuen, Nature (London) 407, 57 (2000).
- 7N. B. Zhitenev, H. Meng, and Z. Bao, Phys. Rev. Lett. **88**, 226801 (2002).
- 8A. Erbe, C. Weiss, W. Zwerger, and R. H. Blick, Phys. Rev. Lett. 87, 096106 (2001).
- ⁹X. M. H. Huang, C. A. Zorman, M. Mehregany, and M. L. Roukes, Nature (London) 421, 496 (2003).
- 10 A. Isacsson, Phys. Rev. B 64, 035326 (2001).
- 11 A. Isacsson and T. Nord, Europhys. Lett. 66 , 708 (2004) .
- 12 V. Aji, J. E. Moore, and C. M. Varma, cond-mat/0302222 (unpublished).
- 13K. D. McCarthy, N. Prokof'ev, and M. T. Tuominen, Phys. Rev. B 67, 245415 (2003).
- 14D. Fedorets, L. Y. Gorelik, R. I. Shekhter, and M. Jonson, Phys. Rev. Lett. 92, 166801 (2004).
- 15T. Novotny, A. Donarini, and A.-P. Jauho, Phys. Rev. Lett. **90**, 256801 (2003).
- 16A.-P. Jauho, T. Novotny, A. Donarini, and C. Flindt, J. Comput. Electron. **3**, 367 (2004).
- 17T. Novotny, A. Donarini, C. Flindt, and A.-P. Jauho, Phys. Rev. Lett. 92, 248302 (2004).
- ¹⁸C. Flindt, T. Novotny, and A.-P. Jauho, Physica E (Amsterdam) **29**, 411 (2005).
- ¹⁹ A. Donarini, Ph.D. thesis, Technical Univ. of Denmark, Kongens Lyngby, 2004.
- 20A. D. Armour and A. MacKinnon, Phys. Rev. B **66**, 035333

 $(2002).$

- 21C. Flindt, T. Novotny, and A.-P. Jauho, Phys. Rev. B **70**, 205334 $(2004).$
- 22S. Tan, *Quantum Optics Toolbox*, http://www.phy.auckland.ac.nz/ Staff/smt/qotoolbox/download.html
- 23K. Molmer, Y. Castin, and J. Dalibard, J. Opt. Soc. Am. B **10**, 524 (1993).
- ²⁴ R. Dum, P. Zoller, and H. Ritsch, Phys. Rev. A **45**, 4879 (1992).
- 25H. J. Carmichael, *An Open Systems Approach to Quantum Optics* (Springer-Verlag, Berlin, 1993).
- ²⁶ H. M. Wiseman and G. J. Milburn, Phys. Rev. A **47**, 1652 (1993).
- ²⁷H. J. Carmichael, Quantum Semiclassic. Opt. 8, 47 (1996), special issue on stochastic quantum optics.
- ²⁸ C. W. Gardiner and P. Zoller, *Quantum Noise*, 2nd ed. (Springer-Verlag, Berlin, 2000).
- 29D. W. Utami, H.-S. Goan, and G. J. Milburn, Phys. Rev. B **70**, 075303 (2004).
- 30H.-S. Goan, G. J. Milburn, H. M. Wiseman, and H. B. Sun, Phys. Rev. B 63, 125326 (2001).
- ³¹ H.-S. Goan and G. J. Milburn, Phys. Rev. B **64**, 235307 (2001).
- ³² H.-S. Goan, Quantum Inf. Comput. **3**, 121 (2003).
- ³³ H.-S. Goan, Phys. Rev. B **70**, 075305 (2004).
- 34P. Glendinning, *Stability, Instability and Chaos: An Introduction to the Theory of Nonlinear Differential Equations* Cambridge University Press, New York, 1994).
- 35G. H. Golub and C. F. Loan, *Matrix Computations*, 3rd ed. The Johns Hopkins University Press, Baltimore, 1996).
- 36T. Nord, L. Y. Gorelik, R. I. Shekhter, and M. Jonson, Phys. Rev. B 65, 165312 (2002).
- ³⁷ H. Schaefers and W. T. Strunz, Phys. Rev. B **71**, 075321 (2005).
- ³⁸ J. Twamley, D. W. Utami, H.-S. Goan, and G. J. Milburn, New J. Phys. 8, 63 (2006).
- ³⁹ J. M. Elzerman, R. Hanson, L. M. W. van Beveren, B. Witkamp, L. M. K. Vandersypen, and L. P. Kouwenhoven, Nature London) 403, 431 (2004).
- ⁴⁰ H. B. Sun and G. J. Milburn, Phys. Rev. B **59**, 10748 (1999).
- ⁴¹ J. Wabnig, D. V. Khomitsky, J. Rammer, and A. L. Shelankov, Phys. Rev. B 72, 165347 (2005).
- ⁴² A. D. Armour, Phys. Rev. B **70**, 165315 (2004).